

BRFL65R380C

/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	650	V
Drain Current	$I_D(T_C=25^\circ\text{C})$	11	A
Drain Current - Pulsed	I_{DM}	44	A
Gate-Source Voltage	V_{GS}	± 30	V
Single Pulsed Avalanche Energy	E_{AS}	277	mJ
Avalanche Current	I_{AS}	8	A
Power Dissipation	$P_D(T_C=25^\circ\text{C})$	27	W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to 150	
Junction-to-Case	$R_{\theta JC}$	4.6	/W
Junction-to-Ambient	$R_{\theta JA}$	65	/W

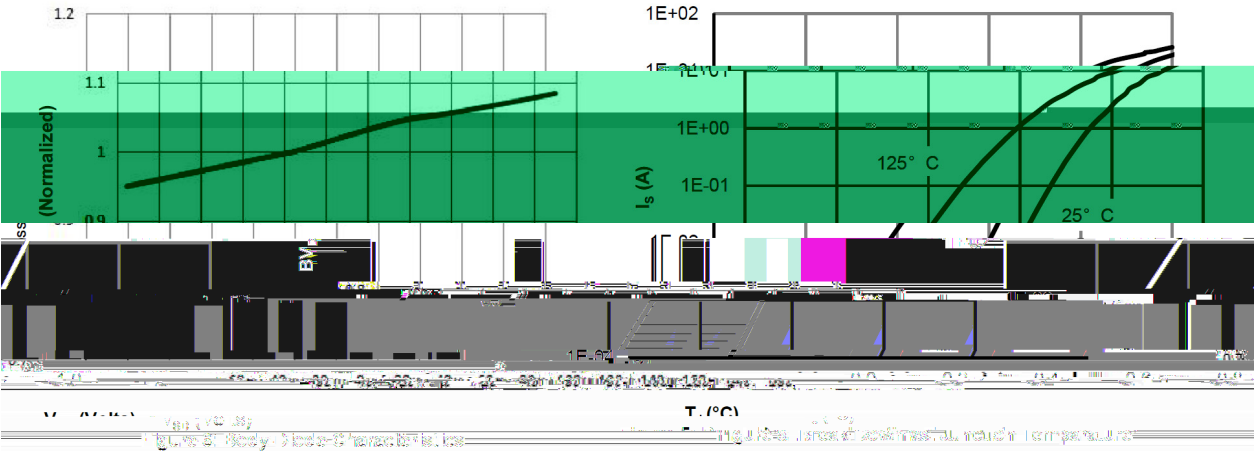
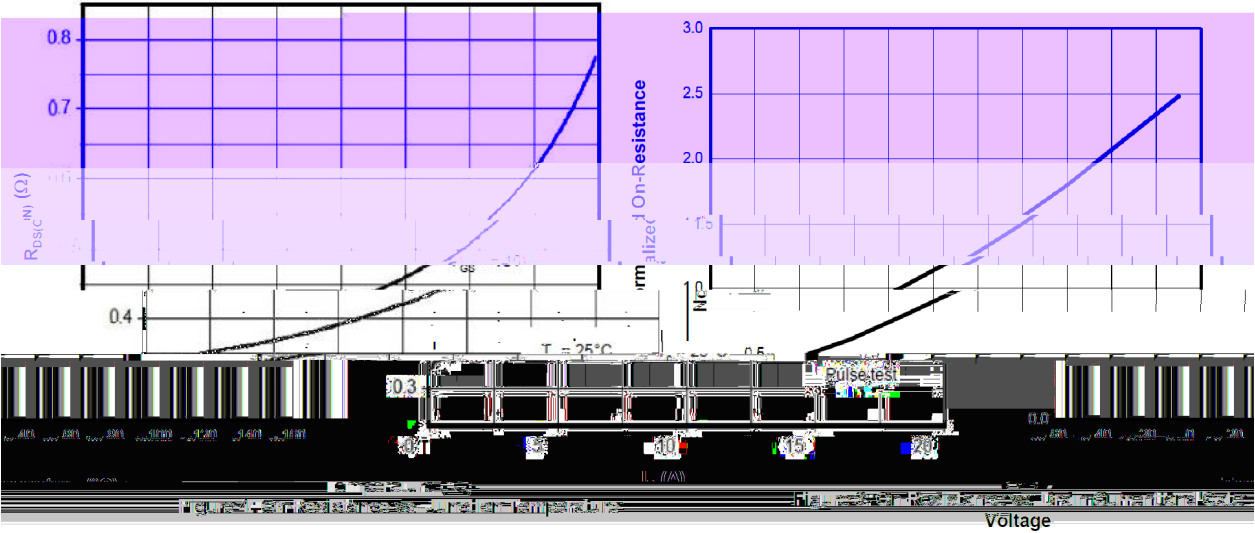
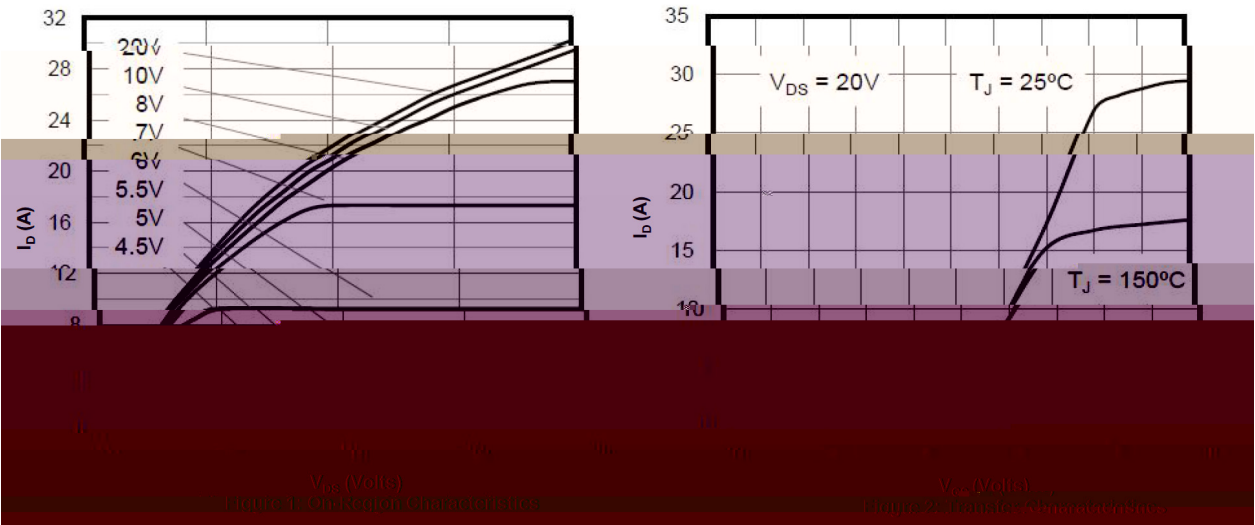
/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DS}	$V_{GS}=0V$ $I_D=250\mu A$	650	700		V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=650V$ $V_{GS}=0V$ $T_J=25^\circ\text{C}$			1.0	μA
Gate-Body Leakage Current, Forward	I_{GSS}	$V_{GS}=\pm 30V$			± 100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu A$	2.5	3.3	4.0	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V$ $I_D=5.5A$		320	380	m Ω
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V$ $I_{SD}=1A$ $T_J=25^\circ\text{C}$			1.2	V
Gate Resistance	R_g	$V_{GS}=0V$ $f=1.0\text{MHz}$		4.1		Ω
Input Capacitance	C_{iss}	$V_{DS}=100V$ $V_{GS}=0V$ $f=1.0\text{MHz}$		735		pF
Output Capacitance	C_{oss}			35		pF
Reverse Transfer Capacitance	C_{rss}			0.45		pF
Turn-On Delay Time	$t_{d(on)}$	$V_{DS}=400V$ $I_D=5.5A$ $R_G=25\Omega$ $V_{GS}=10V$		16.3		ns
Turn-On Rise Time	t_r			35		ns
Turn-Off Delay Time	$t_{d(off)}$			78		ns
Turn-Off Fall Time	t_f			39.5		ns

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Continuous Diode Forward Current	I_S				11	A
Total Gate Charge	Q_g	$V_{DS}=480V \quad I_D=5.5A$ $V_{GS}=10V$		19.2		nC
Gate-Source Charge	Q_{gs}			3.1		nC
Gate-Drain Charge	Q_{gd}			8.2		nC
Reverse recovery time	T_{rr}	$V_R=400V, I_F=5.5A,$ $dI_F/dt=100A/\mu s$		310		ns
Reverse recovery charge	Q_{rr}			2.8		uC

/ Electrical Characteristic Curve



/ Electrical Characteristic Curve

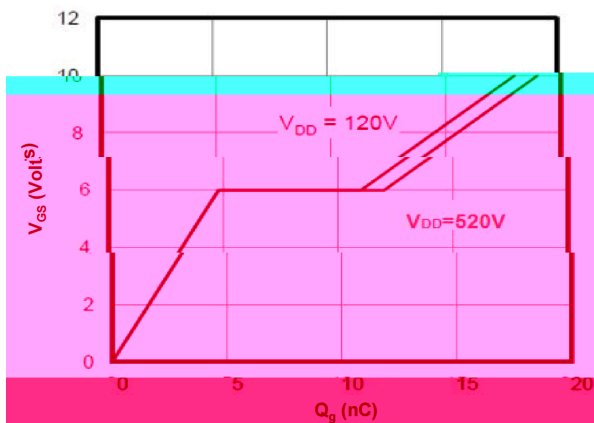


Figure 7: Gate Charge Characteristics

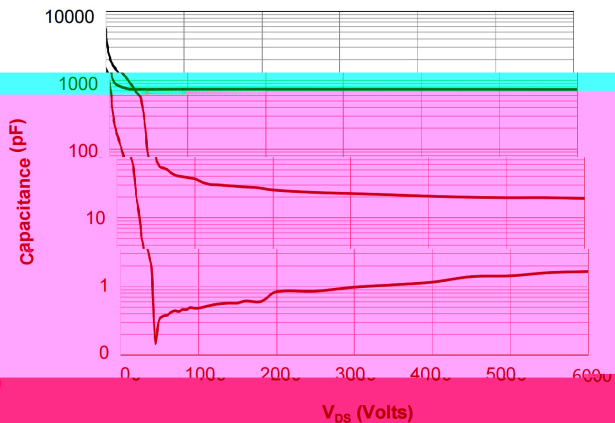


Figure 8: Capacitance Characteristics

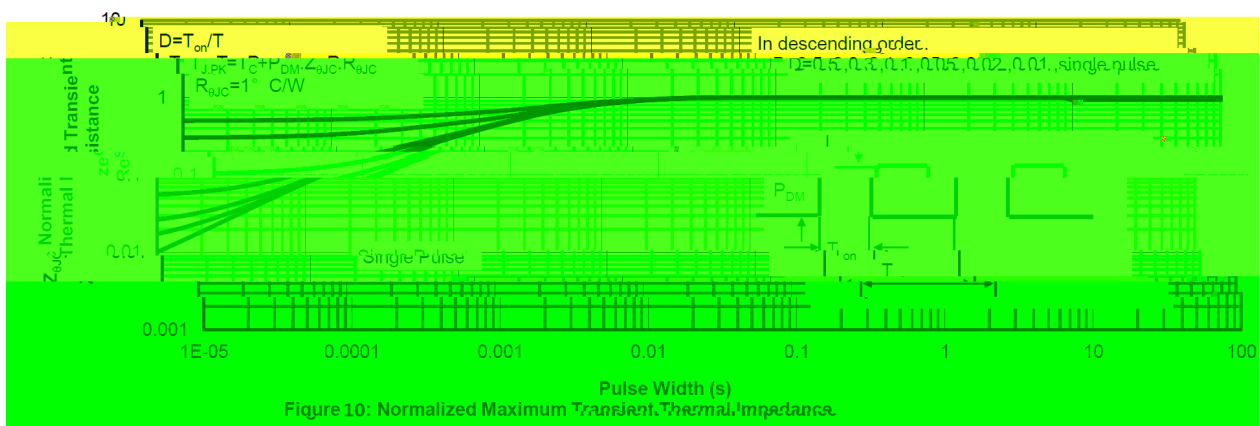
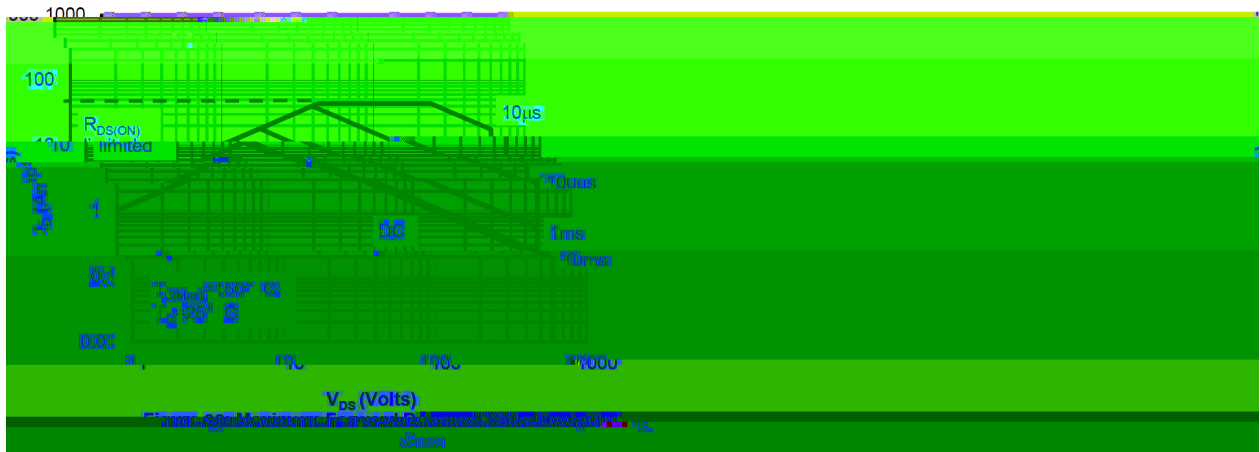
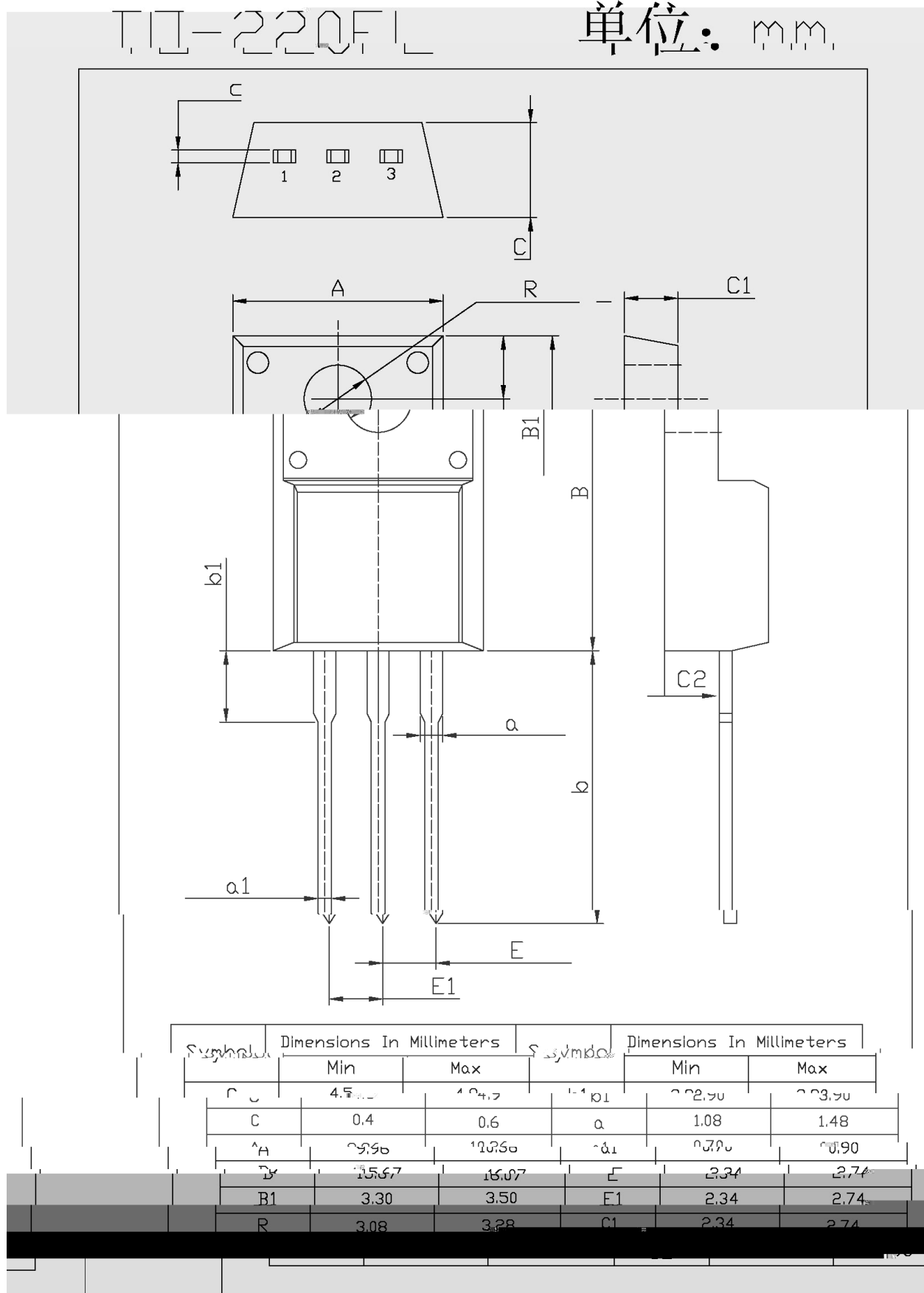
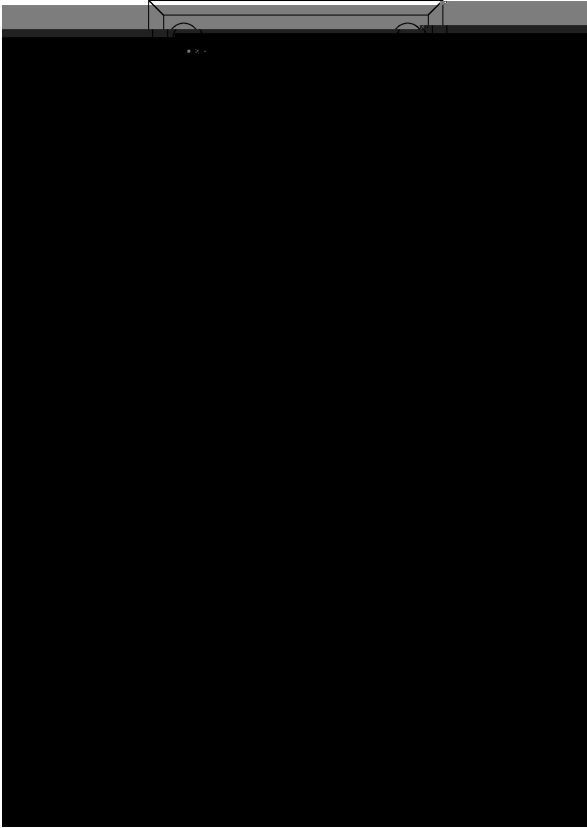


Figure 10: Normalized Maximum Transient Thermal Impedance

/ Package Dimensions



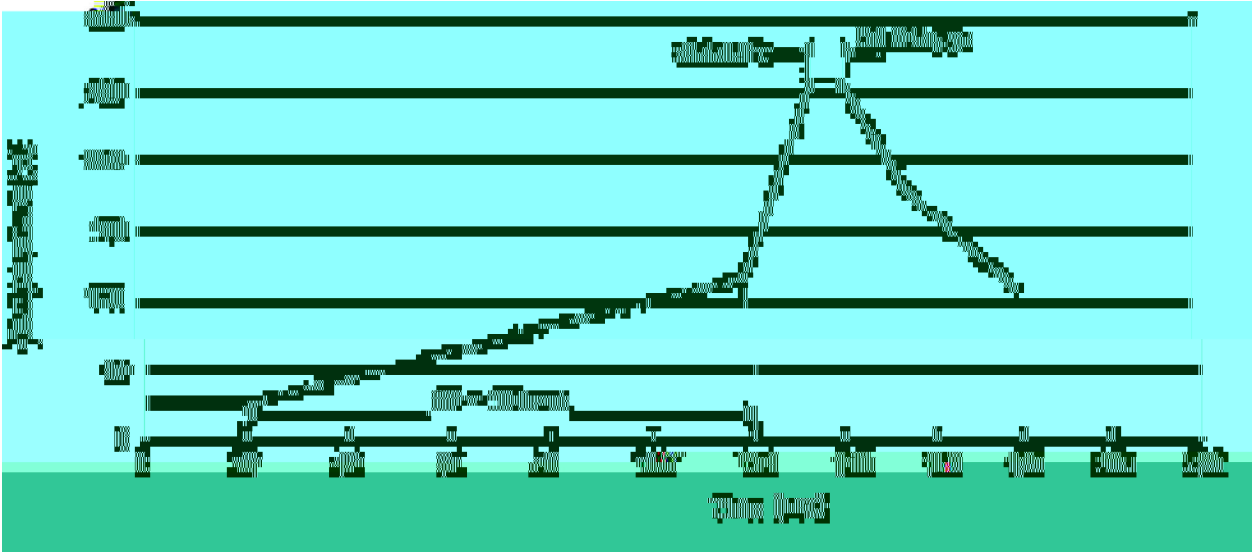
/ Marking Instructions



BR
65R380C

Note:
BR: Company Code
65R380C: Product Type
****: Lot No. Code, code change with Lot No

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- 1

25 150

60 90sec;
- 2

255±5

5±0.5sec;
- 3

2 10

/sec.
- 1.Preheating:25~150

, Time:60~90sec.
- 2.Peak Temp.:255±5

, Duration:5±0.5sec.
3. Cooling Speed: 2~10

/sec.

/ Resistance to Soldering Heat Test Conditions

270±5 10±1 sec. Temp.:270±5 Time:10±1 sec

/ Packaging SPEC.

/ TUBE

Package Type	Units					Dimension (unit mm ³)		
	Units/Tube /	Tubes/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Tube	Inner Box	Outer Box
TO-220FL	50	20	1,000	5	5,000	532×33×7.0	555×164×50	575×290×180

/ Notices